NSN 5961-01-007-6823

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View Online at https://aerobasegroup.com/nsn/5961-01-007-6823

Inclosure Material:

Metal

Overall Length:

Between 1.188 inches and 1.252 inches

Terminal Length:

0.360 inches

Overall Height:

Between 0.250 inches and 0.340 inches

Overall Width:

0.700 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-66

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

400.0 collector to base voltage/static/emitter open and 300.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

2.00 amperes source cutoff current and 500.00 milliamperes source cutoff current

Power Rating Per Characteristic:

20.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Precious Material And Location:

Terminal surface option gold

Precious Material:

Gold

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0